

## NPN PRE-BIASED SMALL SIGNAL SOT-363 DUAL SURFACE MOUNT TRANSISTOR

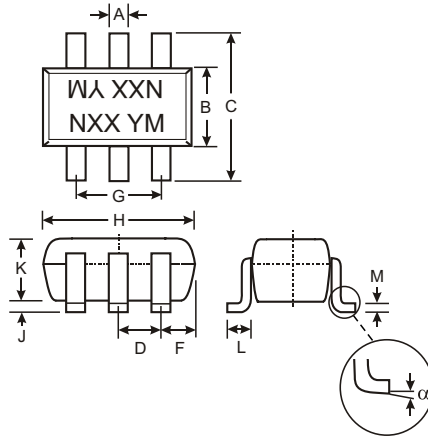
NEW PRODUCT

### Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- Also Available in Lead Free Version

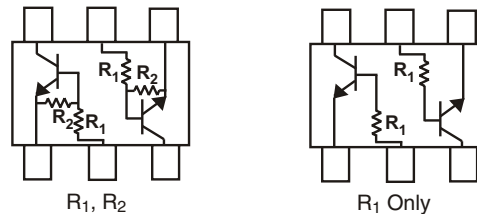
### Mechanical Data

- Case: SOT-363, Molded Plastic
- Moisture sensitivity: Level 1 per J-STD-020A
- Case material - UL Flammability Rating 94V-0
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 4, on Page 3
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 3)
- Weight: 0.006 grams (approx.)
- Ordering Information (See Page 3)



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	0°	8°
All Dimensions in mm		

P/N	R1	R2	MARKING
DDC124EU	22KΩ	22KΩ	N17
DDC144EU	47KΩ	47KΩ	N20
DDC114YU	10KΩ	47KΩ	N14
DDC123JU	2.2KΩ	47KΩ	N06
DDC114EU	10KΩ	10KΩ	N13
DDC143TU	4.7KΩ	-	N07
DDC114TU	10KΩ	-	N12



SCHEMATIC DIAGRAM

### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	V <sub>CC</sub>	50	V
Input Voltage, (2) to (1)	V <sub>IN</sub>	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5 V <sub>max</sub> -5 V <sub>max</sub>	V
Output Current	I <sub>O</sub>	30 30 70 100 50 100 100	mA
Output Current	I <sub>C</sub> (Max)	100	mA
Power Dissipation (Total)	P <sub>d</sub>	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R <sub>θJA</sub>	625	°C/W
Operating and Storage and Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.  
2. 150mW per element must not be exceeded.

**Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic (DDC143TU & DDC114TU only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50	—	—	V	I <sub>C</sub> = 50μA
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	50	—	—	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5	—	—	V	I <sub>E</sub> = 50μA
Collector Cutoff Current	I <sub>CBO</sub>	—	—	0.5	μA	V <sub>CB</sub> = 50V
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	0.5	μA	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	—	0.3	V	I <sub>C</sub> /I <sub>B</sub> = 2.5mA / 0.25mA I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA DDC143TU DDC114TU
DC Current Transfer Ratio	h <sub>FE</sub>	100	250	600	—	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR <sub>1</sub>	-30	—	+30	%	—
Gain-Bandwidth Product*	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU	V <sub>I(off)</sub>	0.5	1.1	—	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA
	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU		0.5	1.1	—		
Output Voltage	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU	V <sub>O(on)</sub>	—	1.9	3.0	V	V <sub>O</sub> = 0.3, I <sub>O</sub> = 5mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 2mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 1mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 5mA V <sub>O</sub> = 0.3, I <sub>O</sub> = 10mA
	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU		—	1.9	3.0		
Input Current	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU	I <sub>I</sub>	—	—	0.36	mA	V <sub>I</sub> = 5V
	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU		—	—	0.18 0.88 3.6 0.88		
Output Current		I <sub>O(off)</sub>	—	—	0.5	μA	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V
DC Current Gain	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU	G <sub>I</sub>	56	—	—	—	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
	DDC124EU DDC144EU DDC114YU DDC123JU DDC114EU		68	—	—		
Input Resistor (R <sub>1</sub> ) Tolerance		ΔR <sub>1</sub>	-30	—	+30	%	—
Resistance Ratio Tolerance		R <sub>2</sub> /R <sub>1</sub>	-20	—	+20	%	—
Gain-Bandwidth Product*		f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

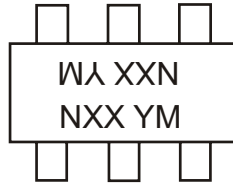
\* Transistor - For Reference Only

**Ordering Information** (Note 3)

Device	Packaging	Shipping
DDC124EU-7	SOT-363	3000/Tape & Reel
DDC144EU-7	SOT-363	3000/Tape & Reel
DDC114YU-7	SOT-363	3000/Tape & Reel
DDC123JU-7	SOT-363	3000/Tape & Reel
DDC114EU-7	SOT-363	3000/Tape & Reel
DDC143TU-7	SOT-363	3000/Tape & Reel
DDC114TU-7	SOT-363	3000/Tape & Reel

- Notes:
- For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
  - For Lead Free version (with Lead Free terminal finish) part number, please add "-F" suffix to part number above.  
Example: DDC114TU-7-F.

**Marking Information**



NXX = Product Type Marking Code  
See Sheet 1 Diagrams  
YM = Date Code Marking  
Y = Year ex: N = 2002  
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**TYPICAL CURVES - DDC123JK  
ONE SECTION**

**NEW PRODUCT**

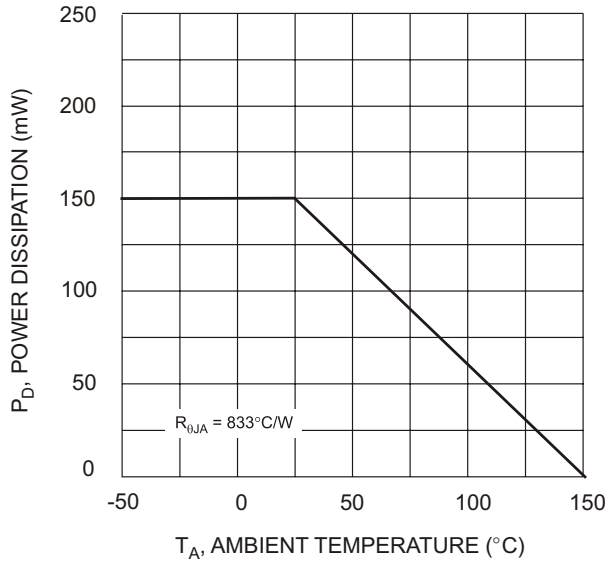


Fig. 1 Derating Curve

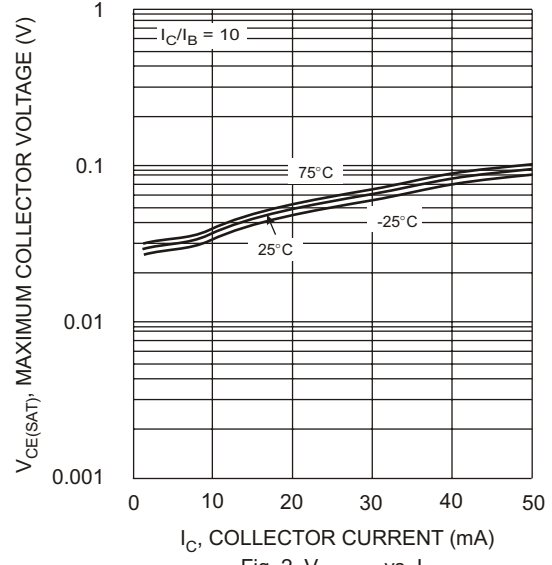


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

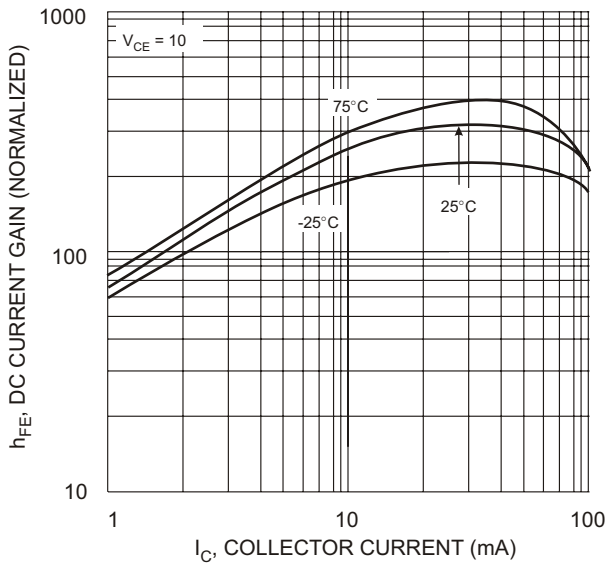


Fig. 3 DC Current Gain

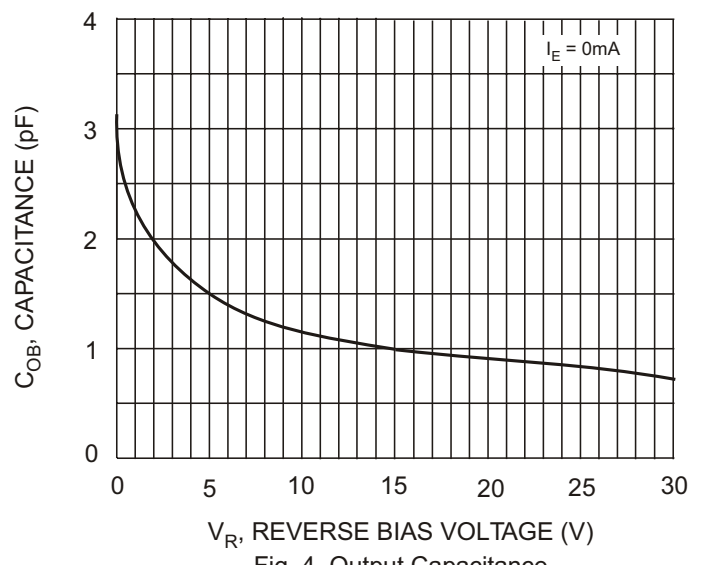


Fig. 4 Output Capacitance

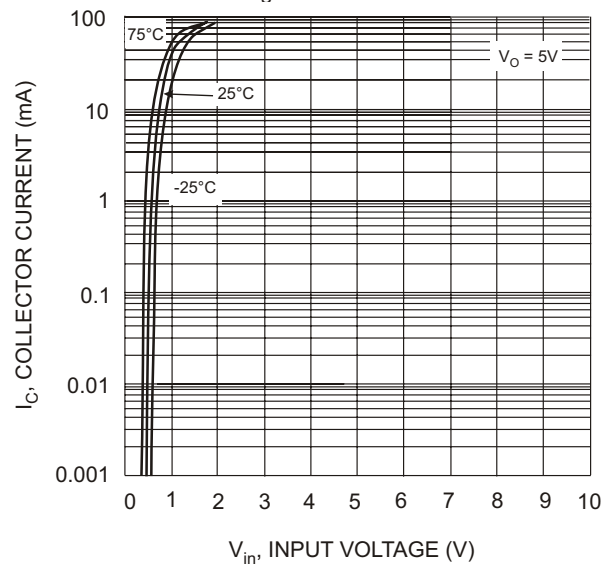


Fig. 5 Collector Current Vs. Input Voltage

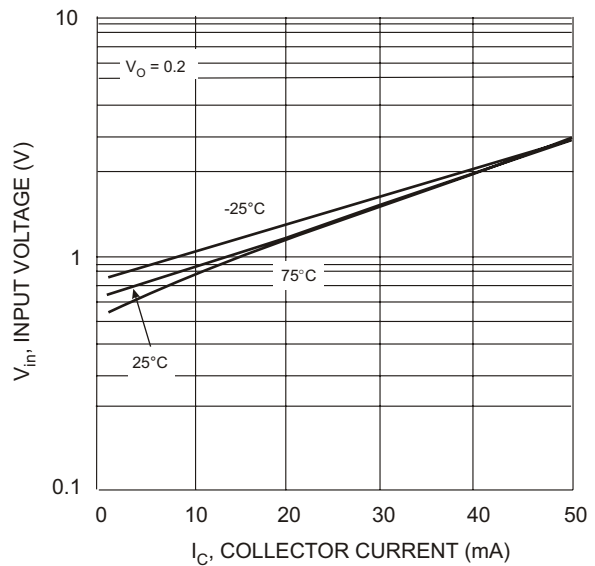


Fig. 6 Input Voltage vs. Collector Current

**TYPICAL CURVES - DDC114TK**

**ONE SECTION**

**NEW PRODUCT**

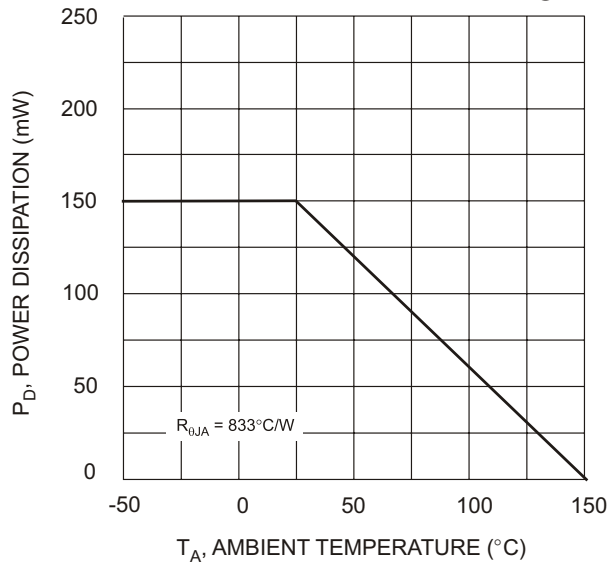


Fig. 1 Derating Curve

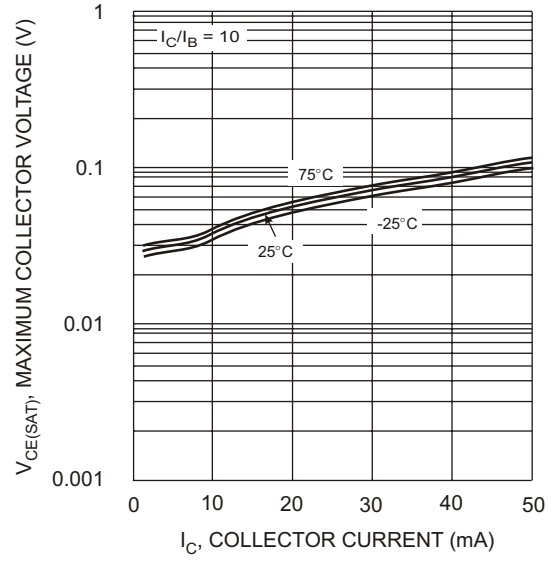


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

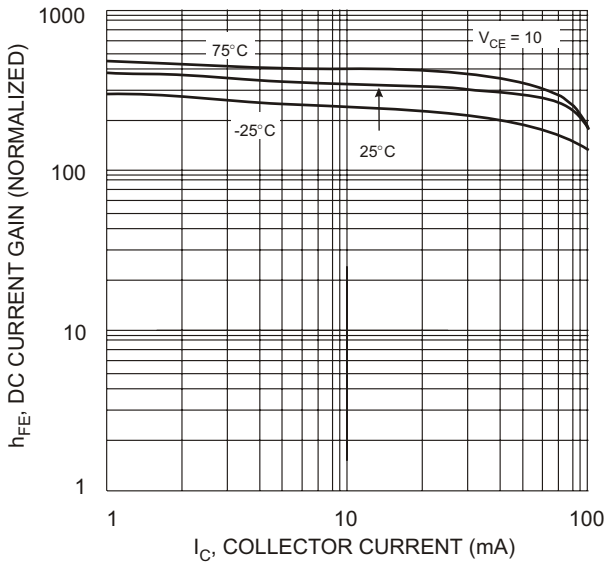


Fig. 3 DC Current Gain

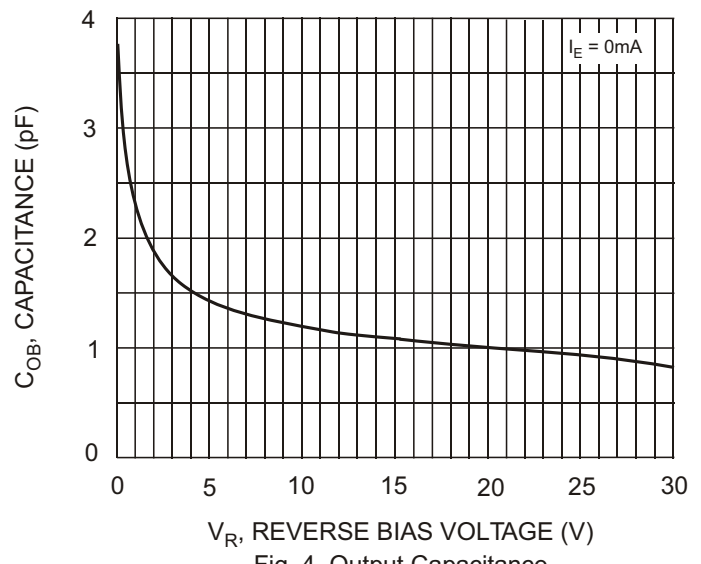


Fig. 4 Output Capacitance

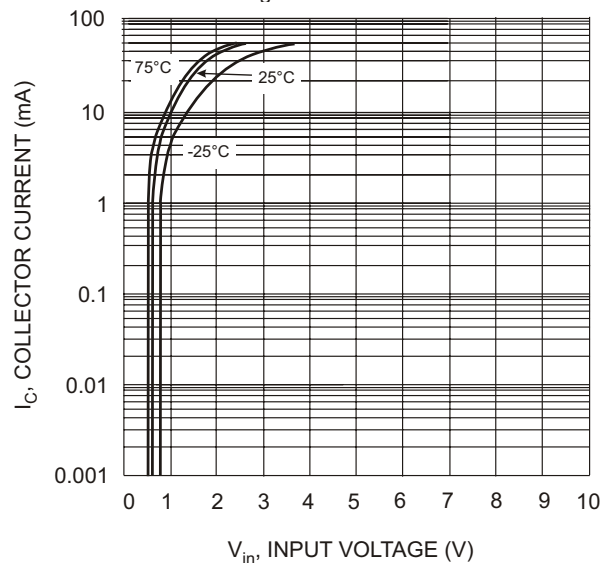


Fig. 5 Collector Current Vs. Input Voltage

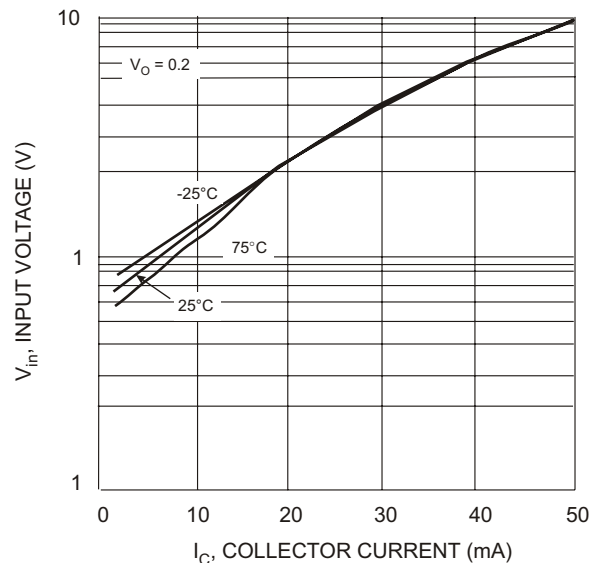


Fig. 6 Input Voltage vs. Collector Current